# TDLNA3024SP

# 2 – 22 GHz Low Noise Amplifier with Adjustable Gain Control

#### **Product Overview**

Teledyne e2v HiRel's TDLNA3024SP is a distributed Low Noise Amplifier with Adjustable Gain Control (AGC) which operates between 2 GHz and 22 GHz.

It is designed for a wide range of applications, such as Space, electronic warfare, X and Ku point to point radio, and test instrumentation.

The circuit is manufactured with a pHEMT process, 0.15 µm gate length, via holes through the substrate, air bridges and electron beam gate lithography.

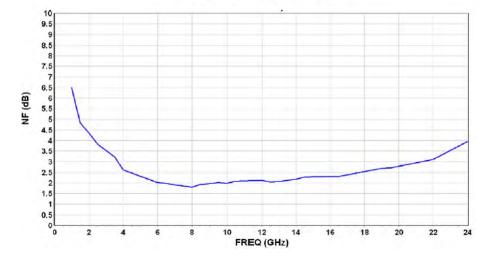
Packaged in a 7 mm x 7 mm 16-Lead hermetic leadless ceramic package.



#### **Features**

- Frequency Range: 2 22 GHz
- Noise Figure: 3 dB (typical)
- Linear Gain: 15 dB (typical)
- Up to 30 dB adjustable gain with V<sub>G2</sub>
- DC Bias: VD = 3.5 V@ IDQ = 100 mA,  $V_{G1}$  = -0.3 V and  $V_{G2}$  = 1.7 V
- · Hermetic ceramic leadless packaging
- Package Dimensions: 7.0 x 7.0 mm
- Radiation Performance: 100kRad (Si)

#### Noise Figure versus Frequency





# **Absolute Maximum Ratings (1)**

Tamb.= +25°C

Symbol	Parameter	Values	Unit
Vd	Drain bias voltage	7V	V
loo	Drain bias current	190	mA
$V_{G1}$	Gate bias voltage	-2 to 0	V
$V_{G2}$	Gate bias voltage (AGC)	-2 to 2	V
P1N	Maximum CW input power overdrive	15	dBm

<sup>(1</sup> Operation of this device above anyone of these parameters may cause permanent damage.

#### **Main Electrical Characteristics**

Tamb.= +25 $^{\circ}$ C Vo=+SV V<sub>G2</sub>= 1.7V V<sub>G</sub>1set to have I<sub>DQ</sub>= 100mA

Symbol	Parameter		Тур	Max	Unit
Freq	Frequency range			22	GHz
Gain	Linear Gain		15		dB
NF	NF Noise Figure 3			dB	
Pout	Output Power@1dB comp.		18		dBm

# **Electrical Specifications**

Tamb.=  $+25^{\circ}$  C Vo=+5V V<sub>G2</sub>=1.7V V<sub>G1</sub> set to have I<sub>DQ</sub>=100mA

Symbol	Parameter	Min	Тур	Max	Unit
Freq	Frequency range	2		22	GHz
Gain	Linear Gain	14	15		dB
ΔG	Gain control		30		dB
NF	Noise Figure		3		dB
IRL	Input Return Loss		10		dB
ORL	Output Return Loss		10		dB
P1dB	Output power for 1dB Gain Compression		18		dBm
P sat	Saturated output power		22		dBm
I <sub>DQ</sub>	Quiescent current on Vd		100		mA
$V_D$	Supply voltage on Vd	4.5	5	5.5	V
I <sub>D</sub>	Drain current @3dB gain compression		125		mA



### Temperature Range)

Та	Operating Temperature Range	-40 to 85	${\mathbb C}$
Tstg	Storage Temperature Range	-55 to 150	$^{\circ}$

## **Typical Bias Conditions**

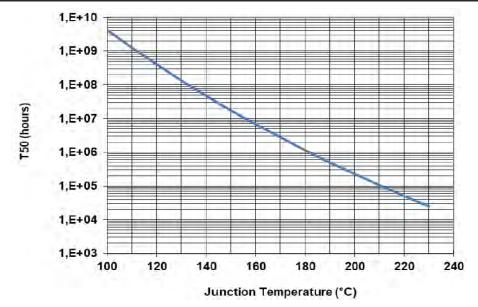
Tamb.= +25°C

Symbol	Pad #	Parameter	Values	Unit
$V_{G1}$	5	Maximum Gain	-0.3	V
$V_{G2}$	18	Mean Value to reach I <sub>DQ</sub> = 100mA	1.7	V
$V_{D}$	14	Drain Bias Voltage	5	V

#### **Device Thermal Performance**

The temperature is monitored at the package back-side interface (Tease). The system maximum temperature must be adjusted in order to guarantee that Tjunction remains below the maximum value specified in the Absolute Maximum Ratings table. So, the system PCB must be designed to comply with this requirement.

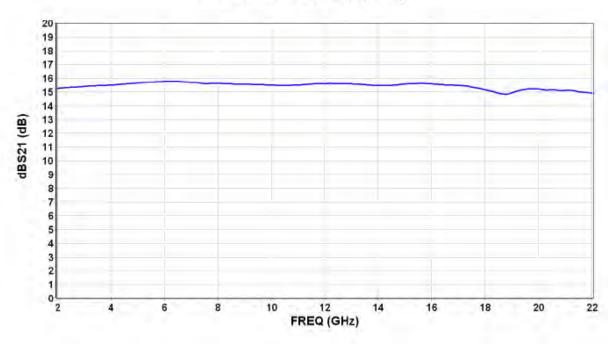
Parameter	Biasing conditions	Tjunction (C)	RTH (C/W	TSO (hours)
R <sub>TH</sub> <sup>(1)</sup> Thermal Resistance (Junction to Case)	Vo=5V lo=100mA Po1ss=0.5W	145	40	3E+07



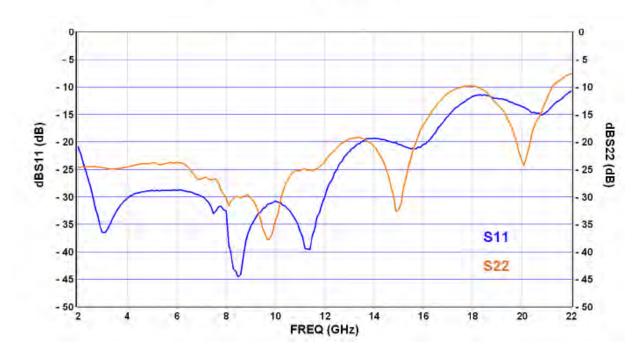


Tamb.= +25° C Vd=+SV  $\rm V_{G2}$ =1.7V  $\rm V_{G1}$  set to have  $\rm I_{DQ}$  = 100mA Measurements in the package access planes

## Linear Gain versus Frequency



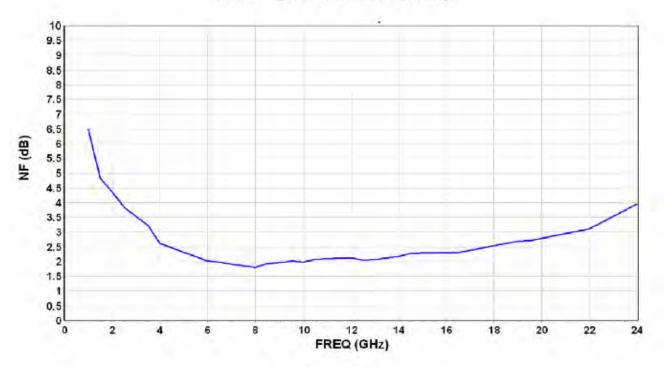
## Return Loss Versus Frequency



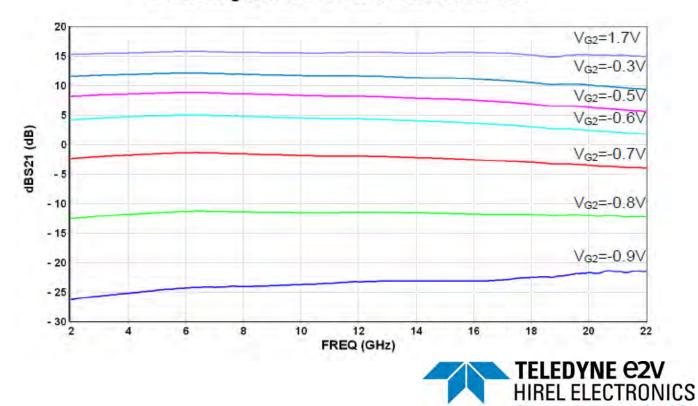


Tamb.= +25° C Vd=+SV  $V_{\rm G2}$ =1.7V  $V_{\rm G1}$  set to have  $I_{\rm DQ}$  = 100mA Measurements in the package access planes

## Noise Figure versus Frequency



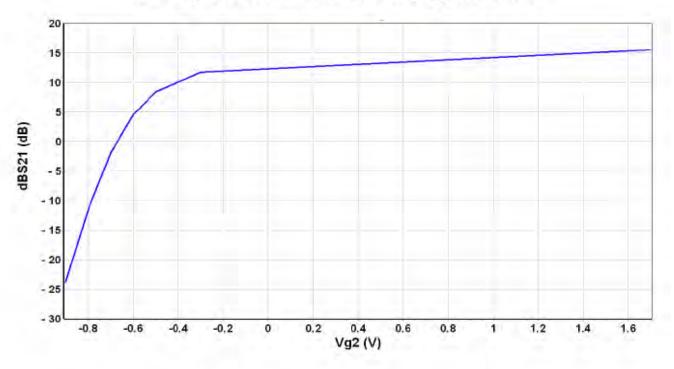
#### Gain tuning with VG2 at VD=+5V and IDQ=100mA



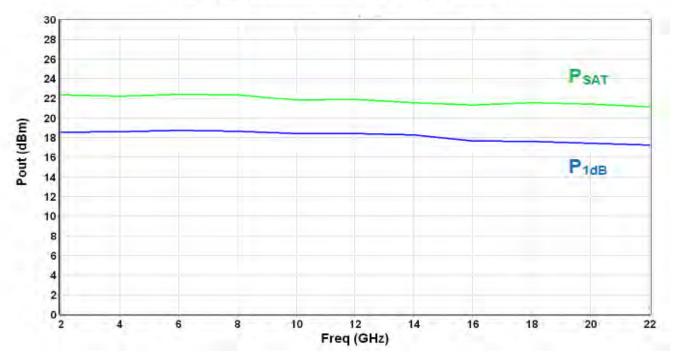
Everywhereyoulook"

Tamb.= +25° C Vd=+SV  $\rm V_{G2}$ =1.7V  $\rm V_{G1}$  set to have  $\rm I_{DQ}$  = 100mA Measurements in the package access planes

# Linear gain versus V<sub>G2</sub> control voltage @freq=10GHz

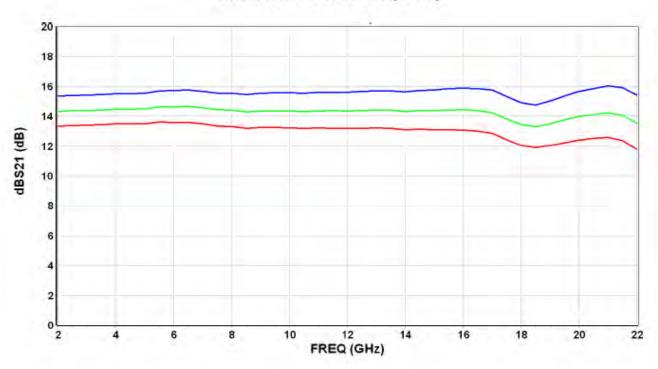


#### Pout compression level versus Frequency

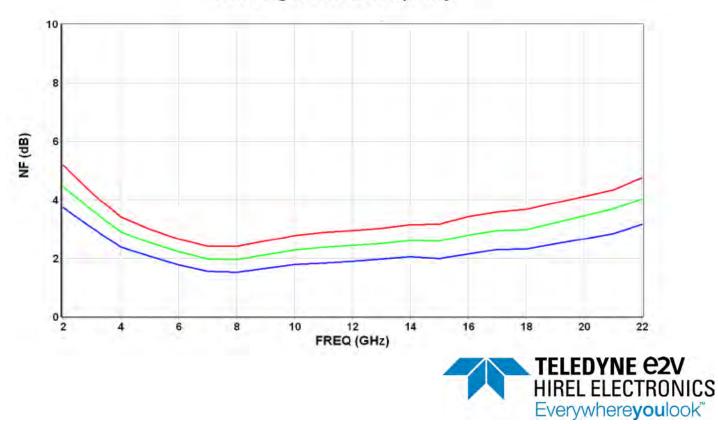


Tamb.= -40 / +25° / +85C Vd=+SV  $V_{G2}$ =1.7V  $V_{G1}$  set to have  $I_{DQ}$  = 100mA Measurements in the package access planes

### Linear Gain versus Frequency

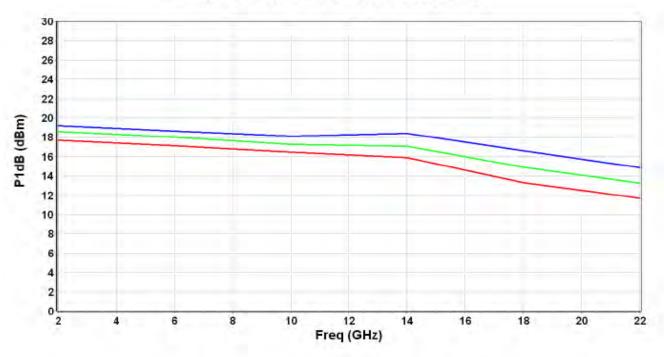


## Noise Figure versus Frequency

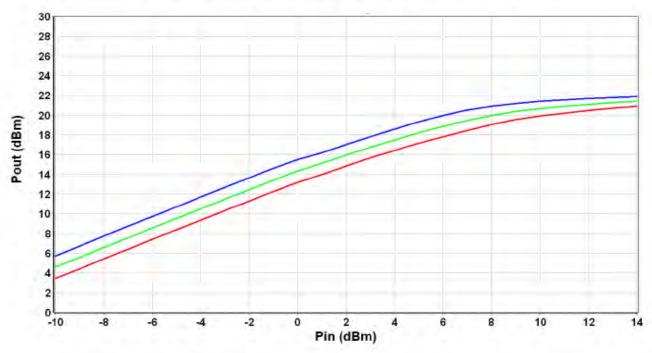


Tamb.= -40 / +25° / +85C Vd=+SV  $V_{G2}$ =1.7V  $V_{G1}$  set to have  $I_{DQ}$  = 100mA Measurements in the package access planes

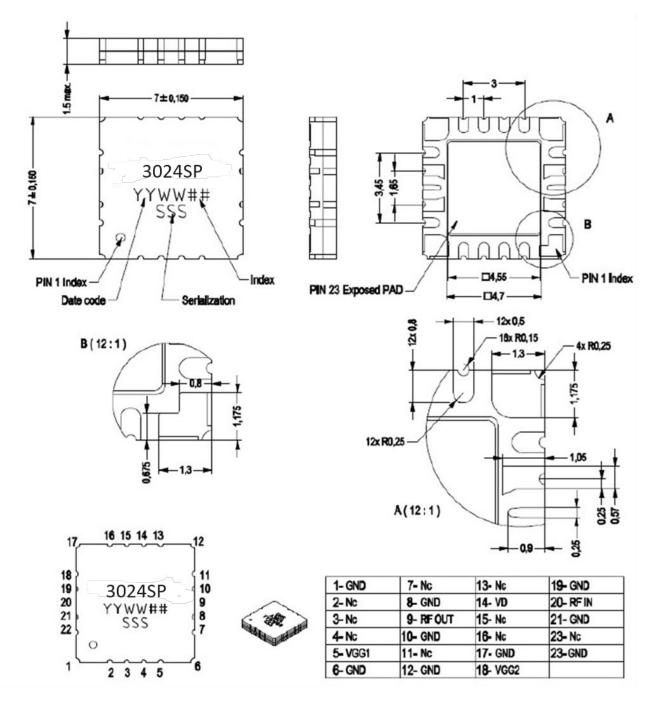
## Output power at 1dBc versus frequency



#### Output power versus Input power @freq=10GHz



# Package Outline 1



All dimensions are in mm

<sup>1</sup> It is strongly recommended to ground all pins marked "Gnd" through the PCB board. Ensure that the PCB board is designed to provide the best possible ground to the package.

#### **Ordering Information**

Order Code	Description	Package	Shipping Method
TDLNA3024SP	2 - 22 GHz Low Noise Amplifier	7 x 7 Ceramic QFN	Tray

#### **Revision Information**

Document	Description / Date	Change/Revision Details
TDLNA3024SP-04-2024 Rev 0.2	TDLNA3024SP / Mar 2024	Initial Release

## **Document Categories and:**

#### **Advance Information**

The product is in a formative or design stage. The data sheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

#### **Preliminary Specification**

The data sheet contains preliminary data. Additional data may be added at a later date. Teledyne e2v HiRel Electronics reserves the right to change specifications at any time without notice in order to supply the best possible product.

#### **Product Specification**

The data sheet contains final data. In the event Teledyne e2v HiRel Electronics decides to change the specifications, Teledyne e2v HiRel Electronics will notify customers of the intended changes by issuing a CNF (Customer Notification Form).

#### **Sales Contact**

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